

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,638,828 B2  
APPLICATION NO. : 10/542041  
DATED : December 29, 2009  
INVENTOR(S) : Jean-Pierre Schoellkopf

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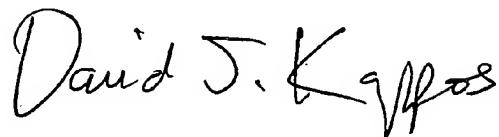
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 1, line 8, should read:  
of capacitors associated with SRAM cells.

Column 7, claim 3, line 50, should read:  
and the second electrodes of which are a same coated region

Signed and Sealed this

Ninth Day of February, 2010



David J. Kappos  
Director of the United States Patent and Trademark Office